**Supplementary materials** 

## Type-II BiVO<sub>4</sub>/Ni<sub>3</sub>(hexahydroxytriphenylene)<sub>2</sub> heterojunction photoanodes for effective photoelectrochemical reaction

Ji Won Yoon, Young-Moo Jo, Jong-Heun Lee\*

Department of Materials Science and Engineering, Korea University, Seoul 02841, Republic of Korea

\*Corresponding author. *E-mail address: jongheun@korea.ac.kr* (Jong-Heun Lee)

## Material characterization

Morphological and structural characterizations of the BiVO<sub>4</sub> film and BiVO<sub>4</sub>/M<sub>3</sub>(HHTP)<sub>2</sub> (M = Ni, Co, Cu) were conducted using a field-emission scanning electron microscope (FE-SEM, SU-70) with an acceleration voltage of 5–10 kV and TEM (JEM-F200, JEOL Ltd, Japan). The phase and crystal structure of the BiVO<sub>4</sub> film and BiVO<sub>4</sub>/M<sub>3</sub>(HHTP)<sub>2</sub> (M = Ni, Co, Cu) were investigated via XRD (D/MAX-2500V/PC, Rigaku, Japan; Cu*K* $\alpha$ ,  $\lambda$ =1.5418 Å). The atomic compositions of the BiVO<sub>4</sub>/M<sub>3</sub>(HHTP)<sub>2</sub> (M = Ni, Co, Cu) were analyzed by XPS (X-TOOL, ULVAC-PHI, monochromatic Al-K $\alpha$  = 1486.6 eV, Ag 3d5/2 < 0.48 eV). The reflection (R) and transmission (T) of the photoanodes were obtained using UV-vis spectroscopy (UV-vis, Jasco V-650). The band-bending diagrams of the BiVO<sub>4</sub>/M<sub>3</sub>(HHTP)<sub>2</sub> (M = Ni, Co, Cu) were investigated using ultraviolet photoelectron spectroscopy (UPS, AXIS-Nova; monochromatic He 1 = 21.2 eV, Ag 3d<sub>5/2</sub> < 100 meV) and UV-vis spectroscopy.

## PEC measurements

PEC water splitting was conducted in a 0.1 M Na<sub>2</sub>SO<sub>3</sub> and 0.1 M Na<sub>2</sub>SO<sub>4</sub> solution using a threeelectrode electrochemical system (Ivium Technologies) equipped with BiVO<sub>4</sub>/M<sub>3</sub>(HHTP)<sub>2</sub> (M = Ni, Co, Cu) as the working electrode, a Pt mesh as the counter electrode, and Ag/AgCl/saturated NaCl as the reference electrode. A filter with the standard solar radiation of air mass (AM) 1.5 G was installed in the solar simulator, which was calibrated to 1 sun (100 mW/cm<sup>2</sup>). The photoanodic performance was measured in the dark and under illumination using linear sweep voltammetry (LSV) at a scan rate of 20 mVs<sup>-1</sup>. The measured potential vs. Ag/AgCl was converted to RHE using the Nernst equation:

$$E_{RHE} = E_{Ag/AgCl} + E_{Ag/AgCl} + 0.059 * pH,$$
(1)

where  $E_{RHE}$  is the converted potential vs. RHE,  $E_{Ag/AgCl}^{o} = 0.1976$  V, and  $E_{Ag/AgCl}$  is the measured potential vs. RHE and the Ag/AgCl reference. The IPCE was measured at an applied voltage of 1.23 V

vs. RHE under the irradiation source and monochromator (MonoRa150). The intensity at each wavelength was measured using a calibrated Si photodiode. The IPCE was calculated using the following equation:

$$IPCE (\%) = \frac{I_{ph}(mA \ cm^{-2}) \times 1239.8 \ (V \ nm)}{P_{mono} \ (mW \ cm^{-2}) \times \lambda \ (nm)} \times 100,$$
(2)

where  $I_{ph}$  is the measured photocurrent density,  $\lambda$  is the wavelength of the incident light, and  $P_{mono}$  is the power intensity of the incident light at each wavelength. The IPCE considers three main factors: the light absorption efficiency ( $\eta_{abs}$ ), charge separation efficiency ( $\eta_{sep}$ ), and charge transfer efficiency ( $\eta_{trans}$ ).

$$IPCE(\lambda) = \eta_{abs} \times \eta_{sep} \times \eta_{trans}$$
(3)

Electrochemical impedance spectroscopy (EIS) was performed in the frequency range of 100 kHz to 1 Hz with an applied voltage of 1.23 V vs. RHE. The EIS curves were fitted and analyzed to obtain the series resistance ( $R_s$ ,  $\Omega$  cm<sup>2</sup>) and charge transfer resistance at the interface between the electrode and the electrolyte ( $R_{ct}$ ,  $\Omega$  cm<sup>2</sup>). The product of the light-absorption and charge separation efficiencies ( $\eta_{abs} \times \eta_{sep}$ ) and value of  $\eta_{trans}$  were obtained in 0.1 M Na<sub>2</sub>SO<sub>3</sub> solution as a fast hole scavenger.



Fig. S1. (a) Photograph of  $BiVO_4/FTO/glass$  substrate. (b) XRD patterns of electrodeposited  $BiVO_4$  on FTO/glass substrate.



**Fig. S2.** (a) Top-view and (b) cross-sectional view SEM image of  $BiVO_4$  thin film. (c) HR-TEM image of  $BiVO_4$  (inset: SAED patterns). Elemental mappings of (d1)  $BiVO_4$ , (d2) Bi, (d3) V, and (d4) O.



**Fig. S3.** (a) XRD patterns of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub> heterostructure (solvothermal 3.5 h and 6 h). (b) Close examination of XRD peaks at  $2\theta$ =5~20° of BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub> (solvothermal 6 h).



Fig. S4. XPS of (a) Bi 4f, (b) V 2p, (c) O 1s, and (d) Ni 2p in  $BiVO_4/Ni_3(HHTP)_2$  heterostructure.



Fig. S5. XPS of (a) Bi 4f, (b) V 2p, (c) O 1s, and (d) Cu 2p in  $BiVO_4/Cu_3(HHTP)_2$  heterostructure.



Fig. S6. XPS of (a) Bi 4f, (b) V 2p, (c) O 1s, and (d) Cu 2p in  $BiVO_4/Co_3(HHTP)_2$  heterostructure.



Fig. S7. (a) Top-view and (b) cross-sectional view SEM image of  $BiVO_4/Ni_3(HHTP)_2$  heterostructure (solvothermal 1 h). (c) Top-view and (d) cross-sectional view SEM image of  $BiVO_4/Ni_3(HHTP)_2$  heterostructure (solvothermal 6 h).



Fig. S8. *J*-V curves of  $BiVO_4/Ni_3(HHTP)_2$  (solvothermal 1 h and 6 h) heterostructure in a 0.1 M  $Na_2SO_3$ .



**Fig. S9.** (a) J-V curves of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub> in a 1 M Na<sub>2</sub>SO<sub>4</sub> electrolyte (without hole scavenging Na<sub>2</sub>SO<sub>3</sub>). (b) Mott-Schottky plots of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub> at 100 Hz.



**Fig. S10.** (a) J-V curves of  $BiVO_4$ ,  $Ni_3(HHTP)_2$  and  $BiVO_4/Ni_3(HHTP)_2$  in dark (0.1 M  $Na_2SO_4$  electrolyte). (b) J-V curves of  $BiVO_4$ ,  $Ni_3(HHTP)_2$  and  $BiVO_4/Ni_3(HHTP)_2$  in dark (0.1 M  $Na_2SO_3$  electrolyte).

Photoanode	$J_{sulfite}$	$J_{water}$	Ref
	$@1.23 V (mA/cm^2)$	$@ 1.23 V (mA/cm^2)$	
BiVO <sub>4</sub> /Ni <sub>3</sub> (HHTP) <sub>2</sub>	4.66	3.10	This work
BiVO <sub>4</sub> /Bi-MOF	3.21	2.35	[S1]
Fe-doped BiVO <sub>4</sub> /MIL-53(Fe)	-	1.15	[S2]
BiVO <sub>4</sub> /MIL-101(Fe)	-	2.59	[S3]
BiVO <sub>4</sub> /Co-Ni-MOF	-	3.20	[S4]
BiVO <sub>4</sub> @Co-MIm		3.16	[S5]
BiVO <sub>4</sub> /Co-MOF	-	3.10	[S6]
Fe/W-doped BiVO <sub>4</sub> /MIL-100(Fe)	-	2.76	[S7]

**Table S1.** Photocurrent densities of  $BiVO_4/MOF$  heterostructures at 1.23 V in the literatures and the present work. [S1-S7]



Fig. S11. (a) EIS analysis for  $BiVO_4$  and  $BiVO_4/Ni_3(HHTP)_2$  at 0V in dark. (b) Mott-Schottky plots of  $BiVO_4$  and  $BiVO_4/Ni_3(HHTP)_2$  at 100 Hz.



Fig. S12. (a) J-V curves of  $BiVO_4/Co_3(HHTP)_2$  and  $BiVO_4/Cu_3(HHTP)_2$  (front and back illumination) in a 0.1 M Na<sub>2</sub>SO<sub>3</sub> electrolyte. (b) IPCE of  $BiVO_4/Co_3(HHTP)_2$  and  $BiVO_4/Cu_3(HHTP)_2$ . EIS analysis of (c)  $BiVO_4/Co_3(HHTP)_2$  and (d)  $BiVO_4/Cu_3(HHTP)_2$  (front and back illumination).

Photoanode	$R_s(W \cdot cm^2)$	$R_{ct}(W \cdot cm^2)$
BiVO <sub>4</sub> /Co <sub>3</sub> (HHTP) <sub>2</sub> (front)	11.9	1124.8
BiVO <sub>4</sub> /Co <sub>3</sub> (HHTP) <sub>2</sub> (back)	9.8	743.6
BiVO <sub>4</sub> /Cu <sub>3</sub> (HHTP) <sub>2</sub> (front)	10.5	1408.3
BiVO <sub>4</sub> /Cu <sub>3</sub> (HHTP) <sub>2</sub> (back)	11.4	803.2

 Table S2. Fitted charge transfer resistance.



Fig. S13. (a) Pellets of Ni<sub>3</sub>(HHTP)<sub>2</sub> ,Co<sub>3</sub>(HHTP)<sub>2</sub>, and Cu<sub>3</sub>(HHTP)<sub>2</sub>. (b) I-V curves of Ni<sub>3</sub>(HHTP)<sub>2</sub>,Co<sub>3</sub>(HHTP)<sub>2</sub>, and Cu<sub>3</sub>(HHTP)<sub>2</sub> pellets. Electrical measurements of HHTP-based MOFs are performed using two-electrode in air at a constant temperature of 297 K and in the absence of light. The electrical conductivity is calculated to be  $\sigma$ =4.45×10<sup>-6</sup> S cm<sup>-1</sup>,  $\sigma$ =1.59×10<sup>-7</sup> S cm<sup>-1</sup>,  $\sigma$ =4.29x10<sup>-8</sup> S cm<sup>-1</sup> for Ni<sub>3</sub>(HHTP)<sub>2</sub>,Co<sub>3</sub>(HHTP)<sub>2</sub>, and Cu<sub>3</sub>(HHTP)<sub>2</sub>, respectively. ( $\sigma$  = L/(R× $\pi$ (d/2)<sup>2</sup>), L = 2.0 mm, d = 3.0 mm, R<sub>Ni3(HHTP)2</sub>= 6.35×10<sup>5</sup> Ω, R<sub>Co3(HHTP)2</sub>= 1.78×10<sup>7</sup> Ω, R<sub>Cu3(HHTP)2</sub>= 6.59×10<sup>7</sup> Ω)



**Fig. S14.** UPS spectra of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Co<sub>3</sub>(HHTP)<sub>2</sub> for obtaining (a) work function (*f*) and valence band maximum. (c) UV-vis spectra of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Co<sub>3</sub>(HHTP)<sub>2</sub>. Schematic energy band diagram of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Co<sub>3</sub>(HHTP)<sub>2</sub>(d) before contact and (e) after contact.



**Fig. S15.** UPS spectra of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Cu<sub>3</sub>(HHTP)<sub>2</sub> for obtaining (a) work function (*f*) and valence band maximum. (c) UV-vis spectra of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Cu<sub>3</sub>(HHTP)<sub>2</sub>. Schematic energy band diagram of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Cu<sub>3</sub>(HHTP)<sub>2</sub>(d) before contact and (e) after contact.



**Fig. S16.** (a) Electron flux of AM 1.5 G solar spectrum. (b) Electron flux of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub>. The electron flux of the photoanode is the product of AM 1.5 G electron flux and LHE (%). (c)  $\eta_{abs} \times \eta_{sep}$  of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub>.

Photoanode	Light absorption wavelength (nm)	J <sub>max</sub> (mA/cm <sup>2</sup> )	J <sub>abs</sub> (mA/cm <sup>2</sup> )	$\eta_{abs}$ (%)
BiVO <sub>4</sub>	496	6.44	4.42	68.6
BiVO <sub>4</sub> /Ni <sub>3</sub> (HHTP) <sub>2</sub>	504	6.95	4.89	70.4

**Table S3.** Light absorption wavelength,  $J_{max}$ ,  $J_{abs}$ , and  $\eta_{abs}$  of BiVO<sub>4</sub> and BiVO<sub>4</sub>/Ni<sub>3</sub>(HHTP)<sub>2</sub>.



**Fig. S17.** The chronopotentiometry curve of  $BiVO_4/Ni_3(HHTP)_2$  in a 0.1 M Na<sub>2</sub>SO<sub>3</sub> electrolyte at 1.23 V vs. RHE under front and back illumination.



**Fig. S18.** (a) TEM image and (b-g) elemental mappings of  $BiVO_4/Ni_3(HHTP)_2$  heterostructure after photoelectrochemical reaction.

## Reference

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